


 	<h2 style="color: red;">FDI038AN06A0</h2> <p>Hersteller-Teilenummer: FDI038AN06A0</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 80A TO-262AB</p> <hr/> <p>Datenblätter:  FDI038AN06A0.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 933 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDI038AN06A0
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 60V 80A TO-262AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	933 pcs Stock
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I ² Pak, TO-262AA
Supplier Device-Gehäuse	I2PAK (TO-262)
Verlustleistung (max)	310W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	17A (Ta), 80A (Tc)
Rds On (Max) @ Id, Vgs	3.8 mOhm @ 80A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	124nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	6400pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tube


















































FDI038AN06A0 ist neu im Original, Suche FDI038AN06A0 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDI038AN06A0 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FDI038AN06A0: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDI030N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 120A I2PAK</p>	 <p>FDI038AN06A0 FAIRCHILD FDI038AN06A0 FAIRCHILD</p>	 <p>FDI038AN06A0 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 80A TO-262AB</p>	 <p>FDI040N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 120A I2PAK</p>
 <p>FDI030N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 120A I2PAK</p>	 <p>FDI045N10A AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 120A I2PAK-3</p>	 <p>FDI045N10A Fairchild/ON Semiconductor MOSFET N-CH 100V 120A I2PAK-3</p>	 <p>FDI040N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 120A I2PAK</p>

heiße Teile

Mehr

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 C1608X7R1H152K	 C2012C0G1H102J060AA	 CL21C472JAFNNNF	 D3501N42T	 DZ2J240MOL
 F6KA2G605A4LA-Z	 FDI030N06	 FDI030N06	 FDI038AN06A0	 FDI038AN06A0
 FDI040N06	 FDI040N06	 GRM033R71H471MA12D	 GRM219D71C225KA12D	 GRM21BB10J475MA11L
 IRFK6H054	 IRKC91/08	 IRKJ56-14	 KA1000A800V	 LTC1387IG
 LTC2859CDD#PBF	 MAPDCT0010	 MC14521BCPG	 MC74LCX573DTR2G	 MDS250-16
 MT6601CA/A	 MXL1013DS8+T	 NFW31SP506X1E4L	 PCSB25201T-100MS	 PKGS-00RA-TC
 RHP030N03FRA	 RT9161A-3CPX	 RT9198-15GBG	 RTE24730	 SD703C25S30LPBF
 SMSF1231XT1	 SN74154N	 T729N36TOF	 TC58NVG2S0HTA10	 TDA2822M
 TDB6HK124N16RR	 TPS54980PWPR	 TT142N1000KOF	 TT60N1000KOF	 VUO60-16N01

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